

Abstract Submitted
for the MAR17 Meeting of
The American Physical Society

Fluctuations and topological defects in proper ferroelectric crystals¹ SERGEI PROKHORENKO, YOUSRA NAHAS, LAURENT BELLAICHE, Physics Department and Institute for Nanoscience and Engineering, University of Arkansas — In this work we use a combination of homotopy theory and first-principles-based effective Hamiltonian simulations to investigate the stability of topological defects in proper ferroelectric crystals. Taking BaTiO₃ as a model example, we show that, despite a nearly trivial topology of the order parameter space, these materials can exhibit stable topological point defects in their tetragonal polar phase and stable topological line defects in their orthorhombic polar phase. Stability of such defects originate from a novel mechanism of topological protection related to finite- temperature fluctuations of local dipoles.

¹This work is financially supported by DARPA grant HR0011-15-2-0038 and ARO grant W911NF-12-1-0085

Sergei Prokhorenko
Physique Théorique des Matériaux, Université de Liège

Date submitted: 09 Nov 2016

Electronic form version 1.4